

MIC4126/27/28

Dual 1.5A-Peak Low-Side MOSFET Drivers in Advanced Packaging

Features

- Dual 1.5A-Peak Drivers
- 4.5V to 20V Operating Range
- Exposed Backside Pad Packaging Reduces Heat
 - ePAD SOIC-8L (θ_{JA} = 58°C/W)
 - ePAD MSOP-8L (θ_{JA} = 60°C/W)
 - VDFN ML[™]-8L (θ_{JA} = 60°C/W)
- Bipolar/CMOS/DMOS Construction
 - 25mV maximum output offset from supply or ground
- Latch-Up Protection to >200mA Reverse Current
- Switches 1000pF in 25ns
- Logic-Input Threshold Independent of Supply Voltage
- Logic-Input Protection to –5V
- 6pF Typical Equivalent Input Capacitance
- Dual Inverting, Dual Noninverting, and Complementary Configurations
 - -40°C to +125°C operating junction temperature range

General Description

The MIC4126, MIC4127, and MIC4128 family are highly-reliable dual 1.5A low-side MOSFET drivers fabricated on Microchip's BiCMOS/DMOS process. The devices feature low power consumption and high efficiency. The MIC4126/27/28 translate TTL or CMOS input logic levels to output voltage levels that swing within 25mV of the positive supply or ground whereas comparable bipolar devices are capable of swinging only to within 1V of the supply. The MIC4126/7/8 is available in three configurations: dual inverting, dual noninverting, and complimentary output.

The MIC4126/27/28 offer pin-compatible as well as smaller footprint replacements for the MIC4426/27/28 with improved packaging and electrical performance. The MIC4126/27/28 are available in exposed pad, EPAD, SOIC-8L and MSOP-8L options as well as a small-size VDFN ML[™]-8L option. The devices have an input operating range of 4.5V to 20V.

Primarily intended for driving power MOSFETs, MIC4426/7/8 drivers are suitable for driving other loads (capacitive, resistive, or inductive) which require low-impedance, high peak current, and fast switching time. The devices can withstand up to 500mA of reverse current (either polarity) without latching and up to 5V noise spikes (either polarity) on ground pins.

Data sheets and support documentation can be found on Microchip's website at www.microchip.com.

Applications

- DC/DC Converters
- Motor Drivers
- Clock Line Driver

Package Types



Functional Block Diagram



The function block diagram contains only four resistors, four capacitors, and 52 transistors. Be sure to ground any unused inputs.

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage	+24V
Input Voltage	$V_{\rm S}$ + 0.3V to GND – 5V
ESD Susceptibility	C C
	, , , , , , , , , , , , , , , , , , ,

Operating Ratings ††

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

†† Notice: The device is not guaranteed to function outside its operating ratings.

Note 1: Devices are ESD sensitive. Handling precautions are recommended. Human body model, $1.5 \text{ k}\Omega$ in series with 100 pF.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: $4.5V \le V_S \le 20V$; $T_A = +25^{\circ}C$, **bold** values indicate full specified temperature range; unless noted. Input voltage slew rate >1V/µs; $C_{OUT} = 1000$ pF. Note 1

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions	
Input							
	V _{IH}	2.4	1.4	_	V	—	
Logic 1 Input Voltage		2.4	1.6	_	V	—	
Logic 0 Input Voltage	V _{IL}	—	1.1	0.8	V	—	
Logic o input voltage		—	1.3	0.8	V	—	
Input Current	I _{IN}	-1	_	1	μA	$0V \leq V_{IN} \leq V_S$	
Output					-		
High Output Voltage	V _{OH}	V _S – 0.025	_	—	V	—	
Low Output Voltage	V _{OL}	—	_	0.025	V	—	
	Б	—	6	10	Ω	I _{OUT} = 10 mA, V _S = 20V	
Output Resistance	R _O	—	8	12			
Peak Output Current	I _{PK}	—	1.5	_	А	—	
Latch-Up Protection	I	>200	_	—	mA	Withstand Reverse Current	
Switching Time							
Rise Time	+	—	13	30		Toot Figure 1.1	
Rise Time	t _R	_	20	40	ns	Test Figure 1-1	
Fall Time	+	—	15	25		Toot Figure 1.1	
	t _F	—	18	40	ns	Test Figure 1-1	
Delay Time	+	_	37	50	ns	Toot Figure 1.1	
	t _{D1}	_	43	60		Test Figure 1-1	
Dolov Timo	+	_	40	60	ns	Toot Figure 1.1	
Delay Time	t _{D2}	_	45	70		Test Figure 1-1	

Note 1: Specification for packaged product only.

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: $4.5V \le V_S \le 20V$; $T_A = +25^{\circ}C$, **bold** values indicate full specified temperature range; unless noted. Input voltage slew rate >1V/µs; $C_{OUT} = 1000$ pF. Note 1

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions		
Power Supply								
Davies Oversky Overset			1.4	4.5				
Power Supply Current	IS	_	1.5	8	mA	$V_{INA} = V_{INB} 3.0V$		
Deuver Current			0.18	0.4				
Power Supply Current	۱ _S		0.19	0.6	mA	$V_{INA} = V_{INb} 0.0V$		

Note 1: Specification for packaged product only.

TEMPERATURE SPECIFICATIONS

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Temperature Ranges							
Maximum Junction Temperature	TJ		—	+150	°C	—	
Storage Temperature Range	Τ _S	-65	—	+150	°C	—	
Lead Temperature	—	—	—	+300	°C	10 sec.	
Junction Operating Temperature Range	TJ	-40	_	+125	°C	_	
Package Thermal Resistances						·	
Thermal Resistance, 3x3 VDFN 8-Ld	θ_{JA}		60	_	°C/W	—	
Thermal Resistance, EP MSOP 8-Ld θ _{JA}			60	_	°C/W	—	
Thermal Resistance, EP SOIC 8-Ld			58	_	°C/W	—	

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

Test Circuits



FIGURE 1-1:

Inverting Driver Switching Time.



FIGURE 1-2:

Noninverting Driver Switching Time.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.





Rise and Fall Time.



FIGURE 2-2: MIC4127 Supply Current vs. Capacitive Load.



Frequency.



FIGURE 2-4: Resistance.

MIC4126 Output



FIGURE 2-5:

Turn On and Turn Off Delay.



FIGURE 2-6: Rise and Fall Time vs. Capacitive Load.



FIGURE 2-7:

Low Output vs. Current.



FIGURE 2-8: Quiescent Power Supply Current vs. Supply Voltage.



FIGURE 2-9:MIC4127 Supply Current vs.Capacitive Load.



FIGURE 2-10: Rise and Fall Time vs. Capacitive Load.



FIGURE 2-11: High Output vs. Current.



FIGURE 2-12: Quiescent Power Supply Current vs. Supply Voltage.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

Pin Number	Pin Name	Description			
1, 8	NC	Not internally connected			
2	INA	Control Input A: TTL/CMOS compatible logic input			
3	GND	Ground			
4	INB	Control Input B: TTL/CMOS compatible logic input			
5	OUTB	Output B: CMOS totem-pole output			
6	V _S	Supply Input: +4.5V to +20V			
7	OUTA	Output A: CMOS totem-pole output			
EP	GND	Ground, backside pad			

TABLE 3-1: PIN FUNCTION TABLE

4.0 APPLICATION INFORMATION

Supply Bypassing

Large currents are required to charge and discharge large capacitive loads quickly. For example, changing a 1000pF load by 16V in 25ns requires 0.8A from the supply input.

To ensure low supply impedance over a wide frequency range, parallel capacitors are recommended for power supply bypassing. Low-inductance ceramic MLC capacitors with short lead lengths (< 0.5") should be used. A 1.0 μ F film capacitor in parallel with one or two 0.1 μ F ceramic MLC capacitors normally provides adequate bypassing.

Grounding

When using the inverting drivers in the MIC4126 or MIC4128, individual ground returns for the input and output circuits or a ground plane are recommended for optimum switching speed. The voltage drop that occurs between the driver's ground and the input signal ground, during normal high-current switching, will behave as negative feedback and degrade switching speed.

The E-pad and ML packages have an exposed pad under the package. It is important for good thermal performance that this pad is connected to a ground plane.

Control Input

Unused driver inputs must be connected to logic high (which can be VS) or ground. For the lowest quiescent current (< 500μ A), connect unused inputs-to-ground. A logic-high signal will cause the driver to draw up to 9mA.

The control input voltage threshold is approximately 1.5V. The control input recognizes 1.5V up to Vs as a logic high and draws less than 1μ A within this range.

Power Dissipation

Power dissipation should be calculated to make sure that the driver is not operated beyond its thermal ratings. Quiescent power dissipation is negligible. A practical value for total power dissipation is the sum of the dissipation caused by the load and the transition power dissipation (PL + PT).

Load Dissipation

Power dissipation caused by continuous load current (when driving a resistive load) through the driver's output resistance is:

PL = IL2 RO

For capacitive loads, the dissipation in the driver is:

$$PL = f CL VS2$$

Transition Dissipation

In applications switching at a high frequency, transition power dissipation can be significant. This occurs during switching transitions when the P-channel and N-channel output FETs are both conducting for the brief moment when one is turning on and the other is turning off.

PT = 2 f VS Q

Charge (Q) is read from the following graph:



Crossover Energy Loss per Transition

5.0 PACKAGING INFORMATION

5.1 Package Marking Information



Legend:	Y YY WW NNN @3 *	Product code or customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC [®] designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package. Pin one index is identified by a dot, delta up, or delta down (triangle
t de la constante de la consta	be carried characters the corpora	t the full Microchip part number cannot be marked on one line, it will l over to the next line, thus limiting the number of available for customer-specific information. Package may or may not include ate logo. () and/or Overbar (¯) symbol may not be to scale.

8-Lead SOICN ePad Package Outline and Recommended Land Pattern











8-Lead MSOP ePad Package Outline and Recommended Land Pattern

8-Lead Very Thin Plastic Dual Flat, No Lead Package (JMA) - 3x3x0.9 mm Body [VDFN] Micrel Legacy Package DFN33-8LD-PL-1

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-1021 A Sheet 1 of 2

8-Lead Very Thin Plastic Dual Flat, No Lead Package (JMA) - 3x3x0.9 mm Body [VDFN] Micrel Legacy Package DFN33-8LD-PL-1

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Ν	IILLIMETER	S	
Dimension	Dimension Limits			MAX
Number of Terminals	Ν		8	
Pitch	е		0.65 BSC	
Overall Height	Α	0.80	0.85	0.90
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3		0.203 REF	
Overall Length	D	3.00 BSC		
Exposed Pad Length	D2	2.25	2.30	2.35
Overall Width	E		3.00 BSC	
Exposed Pad Width	E2	1.50	1.55	1.60
Terminal Width	b	0.20	0.25	0.30
Terminal Length	L	0.35	0.40	0.45
Terminal-to-Exposed-Pad	K	0.20	-	-

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Package is saw singulated

3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1021 A Sheet 1 of 2

8-Lead Very Thin Plastic Dual Flat, No Lead Package (JMA) - 3x3x0.9 mm Body [VDFN] Micrel Legacy Package DFN33-8LD-PL-1

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Ν	IILLIMETER	S		
Dimension	Dimension Limits				
Contact Pitch	E		0.65 BSC		
Optional Center Pad Width	X2			2.35	
Optional Center Pad Length	Y2			1.60	
Contact Pad Spacing	С		2.90		
Contact Pad Width (X8)	X1			0.30	
Contact Pad Length (X8)	Y1			0.85	
Contact Pad to Center Pad (X8)	G1	0.23			
Contact Pad to Contact Pad (X6)	G2	0.35			
Thermal Via Diameter			0.30		
Thermal Via Pitch	EV		1.00		

Notes:

- 1. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-3021 Rev A

APPENDIX A: REVISION HISTORY

Revision A (06/2019)

- Converted Micrel document MIC4126/27/28 (M9999-072605) to Microchip data sheet template DS20006084A.
- Minor grammatical text changes throughout.
- Updated Packaging Information to MCHP standard versions.

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

				Examples:
Device Part No.	<u>X</u> Junction Temp. Range	<u>XX</u> Package	- <u>XX</u> Media Type	 a) MIC4126:1.5A-Peak, Dual Inverting, Low-Side MOSFET Driver in Advanced Packaging, Extended Temperature Range, -40°C to +125°C, RoHS Compliant. MIC4126YME 8-Lead ePad SOIC Package 95/Tube
Device:	Dual 1.5A-Peak Packaging Bipol MIC4126: MIC4127: MIC4128:		ting	MIC4126YME-TR 8-Lead ePad SOIC Package 2500/Reaginge MIC4126YMME 8-Lead ePad MSOP Package 100/Tube MIC4126YMME-TR8-Lead ePad MSOP Package 2500/Reel MIC4126YML-TR 8-Lead VDFN Package 5000/Reel b) MIC4127:1.5A-Peak, Dual Noninverting, Low-Side MOSFET Drive in Advanced Packaging, Extended Temperature Range, -40°C to
Junction Temperature Range:		0	DHS Compliant	HI Advanced Figure Exclude Compliant. +125°C, RoHS Compliant. MIC4127YME 8-Lead ePad SOIC Package 95/Tube MIC4127YME-TR 8-Lead ePad SOIC Package 2500/Reaginge MIC4127YME 8-Lead ePad SOIC Package 100/Tube MIC4127YME 8-Lead ePad MSOP Package 2500/Reaginge MIC4127YME 8-Lead ePad MSOP Package 2500/Reel MIC4127YML-TR 8-Lead VDFN Package 5000/Reel
Package:	MME= 8-Lea	ad ePad SOIC ad ePad MSOP ad VDFN		 MIC4128:1.5A-Peak, Inverting and Noninverting, Low-Side MOSFET Driver in Advanced Packaging, Extended Temperature Range, - 40°C to +125°C, RoHS Compliant.
Media Type:		ube (MME, ePa	ad MŚOP) ME, ePad SOIC)	MIC4128YME 8-Lead ePad SOIC Package 95/Tube MIC4128YME-TR 8-Lead ePad SOIC Package 2500/Reaginge MIC4128YMME 8-Lead ePad MSOP Package 100/Tube MIC4128YMME-TR 8-Lead ePad MSOP Package 2500/Reel MIC4128YML-TR 8-Lead vDFN Package 5000/Reel
L				Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

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ISBN: 978-1-5224-4600-2

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